

# SCT3080KW7 N-channel SiC power MOSFET

V <sub>DSS</sub>	1200V
R <sub>DS(on)</sub> (Typ.)	80mΩ
Ι <sub>D</sub> <sup>*1</sup>	30A
P <sub>D</sub>	159W

# Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

# Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

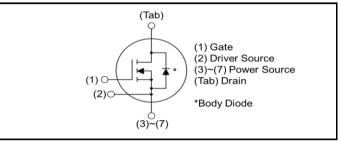
# •Absolute maximum ratings $(T_a = 25^{\circ}C)$

#### Parameter Symbol Value Unit Drain - Source Voltage V<sub>DSS</sub> 1200 V I<sub>D</sub><sup>\*1</sup> $T_c = 25^{\circ}C$ 30 А Continuous Drain current I<sub>D</sub><sup>\*1</sup> $T_{c} = 100^{\circ}C$ 21 А \*2 Pulsed Drain current 75 А I<sub>D,pulse</sub> $\mathsf{V}_{\mathsf{GSS}}$ V Gate - Source voltage (DC) -4 to +22 \*3 Gate - Source surge voltage (t<sub>surge</sub> < 300ns) -4 to +26 V $V_{GSS\_surge}$ V<sub>GS\_op</sub> \*4 V Recommended drive voltage 0/+18T<sub>i</sub> 175 °C Junction temperature $\mathsf{T}_{\mathsf{stg}}$ Range of storage temperature °C -55 to +175

TO-263-7L



### Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

### Packaging specifications

	Packing	Embossed tape
	Reel size (mm)	330
Tuno	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	SCT3080KW7

# •Electrical characteristics ( $T_a = 25^{\circ}C$ )

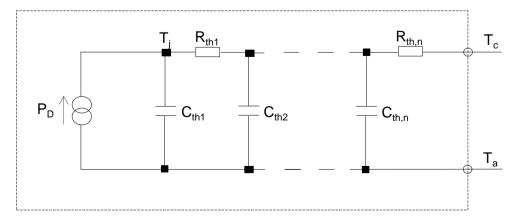
Parameter	Symbol	Conditions		Unit			
Faidilielei	Symbol	Conditions	Min.	Тур.	Max.	Unit	
		$V_{GS} = 0V, I_D = 1mA$					
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	T <sub>j</sub> = 25°C	1200	-	-	V	
		T <sub>j</sub> = -55°C	1200	-	-		
		$V_{GS} = 0V, V_{DS} = 1200V$					
Zero Gate voltage Drain current	I <sub>DSS</sub>	T <sub>j</sub> = 25°C	-	1	10	μA	
		T <sub>j</sub> = 150°C	-	2	-		
Gate - Source leakage current	I <sub>GSS+</sub>	$V_{GS} = +22V, V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I <sub>GSS-</sub>	$V_{GS} = -4V$ , $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = 10V, I_D = 5mA$	2.7	-	5.6	V	
		V <sub>GS</sub> = 18V, I <sub>D</sub> = 10A					
Static Drain - Source on - state resistance	R <sub>DS(on)</sub> *5	$T_j = 25^{\circ}C$	-	80	104	mΩ	
		T <sub>j</sub> = 150°C	-	136	-		
Gate input resistance	R <sub>G</sub>	f = 1MHz, open drain	-	12	-	Ω	

#### •Thermal resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R <sub>thJC</sub>	-	0.73	0.94	°C/W

# •Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	1.08×10 <sup>-1</sup>		C <sub>th1</sub>	4.72×10 <sup>-4</sup>	
R <sub>th2</sub>	3.73×10 <sup>-1</sup>	K/W	C <sub>th2</sub>	3.97×10 <sup>-3</sup>	Ws/K
R <sub>th3</sub>	3.41×10 <sup>-1</sup>		C <sub>th3</sub>	1.31×10 <sup>-2</sup>	





# ●Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Symbol Conditions			Linit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	𝔤 <sub>fs</sub> <sup>∗5</sup>	$V_{DS} = 10V, I_{D} = 10A$	-	4.4	-	S
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0V$	-	785	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 800V	-	75	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	35	-	
Effective output capacitance, energy related	C <sub>o(er)</sub>	$V_{GS} = 0V$ $V_{DS} = 0V$ to 600V	-	74	-	pF
Total Gate charge	$Q_g^{*5}$	$V_{DS} = 600V$ $I_{D} = 10A$	-	60	-	
Gate - Source charge	Q <sub>gs</sub> <sup>*5</sup>	$V_{GS} = 18V$	-	11	-	nC
Gate - Drain charge	$Q_{gd}$ *5	See Fig. 1-1.	-	31	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DS} = 600V$ $I_{D} = 10A$	-	5	-	
Rise time	t <sub>r</sub> *5	V <sub>GS</sub> = 0V/+18V	-	13	-	20
Turn - off delay time	t <sub>d(off)</sub> *5	$R_{G} = 0\Omega, L = 750 \mu H$ L <sub>σ</sub> = 50nH, C <sub>σ</sub> = 10pF	-	20	-	ns
Fall time	t <sub>f</sub> *5	See Fig. 2-1, 2-2, 2-3.	-	12	-	-
Turn - on switching loss	E <sub>on</sub> *5	E <sub>on</sub> includes diode reverse recovery.	-	149	-	
Turn - off switching loss	${\sf E}_{\sf off}$ *5		-	12	-	μJ



# SCT3080KW7

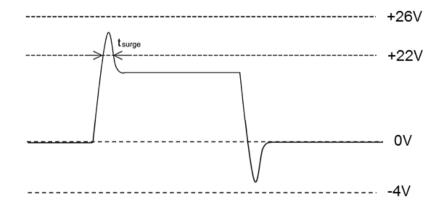
•Body diode electrical characteristics (Source-Drain) ( $T_a = 25^{\circ}C$ )

Deremeter	Symbol	Conditions				
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Body diode continuous, forward current	ا <sub>S</sub> *1	T <sub>c</sub> = 25°C	-	-	30	А
Body diode direct current, pulsed	I <sub>SM</sub> *2	T <sub>c</sub> = 25 C	-	-	75	А
Forward voltage	$V_{SD}$ *5	$V_{GS} = 0V, I_D = 10A$	-	3.2	-	V
Reverse recovery time	t <sub>rr</sub> *5	$I_F = 10A$ $V_R = 600V$	-	17	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 2500A/µs	-	261	-	nC
Peak reverse recovery current	<sup>*5</sup>	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	26	-	A

\*1 Limited by maximum temperature allowed.

\*2  $P_W \leq$  10µs, Duty cycle  $\leq$  1%

\*3 Example of acceptable  $V_{GS}$  waveform



Please note especially when using driver source that  $V_{\text{GSS}\_surge}$  must be in the range of absolute maximum rating.

\*4 Please be advised not to use SiC-MOSFETs with V<sub>GS</sub> below 13V as doing so may cause thermal runaway.

\*5 Pulsed



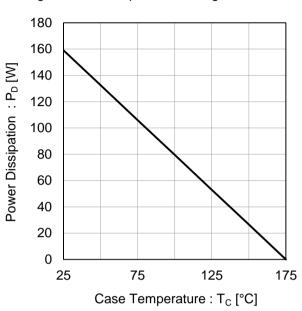
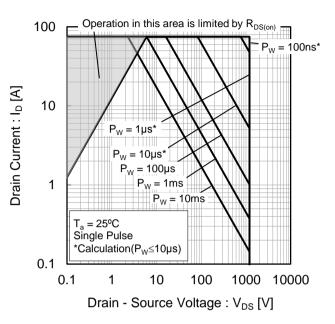
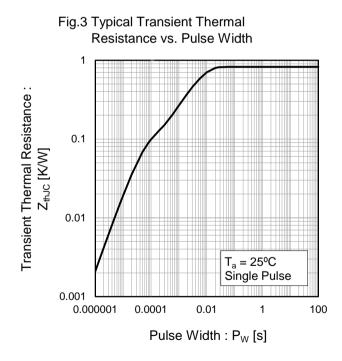


Fig.1 Power Dissipation Derating Curve

#### Fig.2 Maximum Safe Operating Area









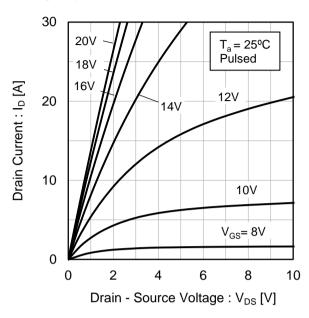


Fig.4 Typical Output Characteristics(I)

Fig.5 Typical Output Characteristics(II)

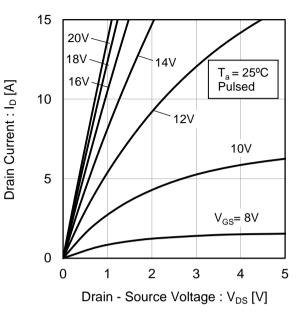
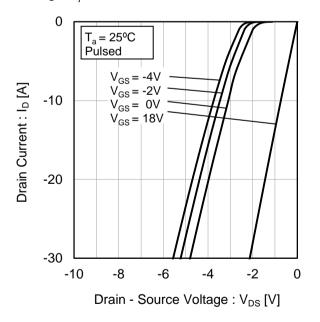
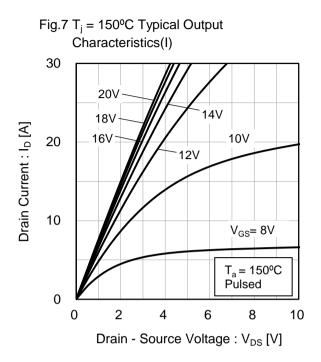


Fig.6 T<sub>i</sub> = 25°C 3rd Quadrant Characteristics







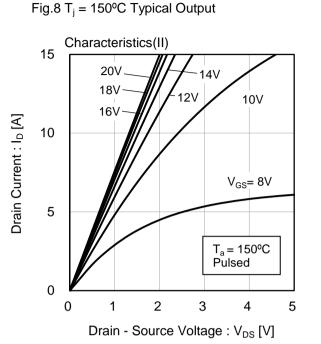
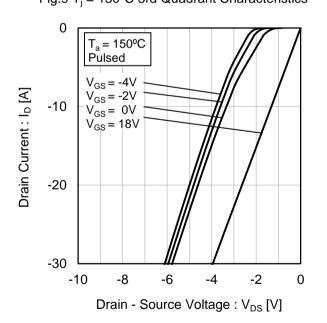
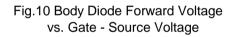
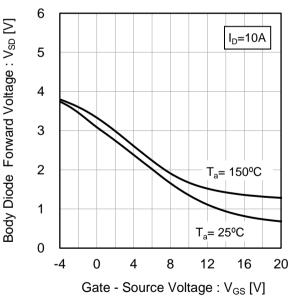


Fig.9  $T_i = 150^{\circ}C$  3rd Quadrant Characteristics









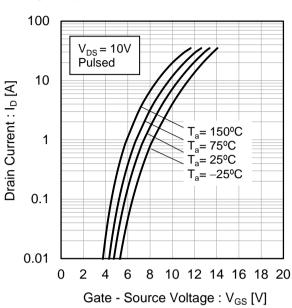
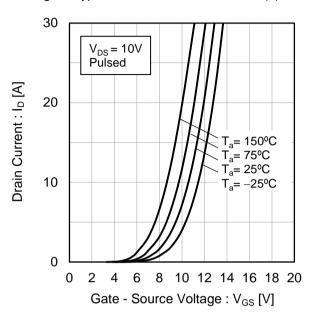


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



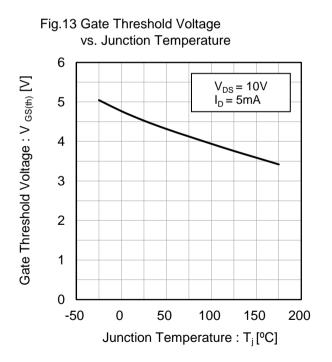
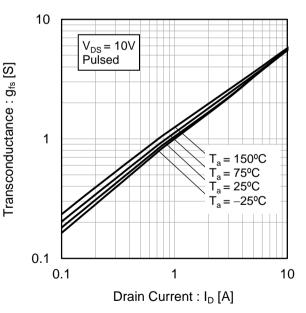
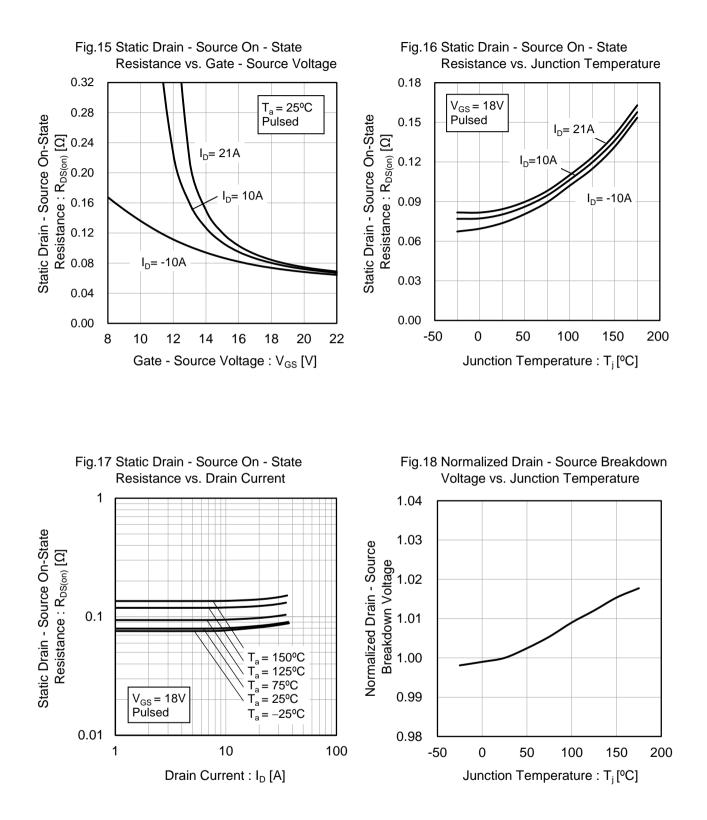


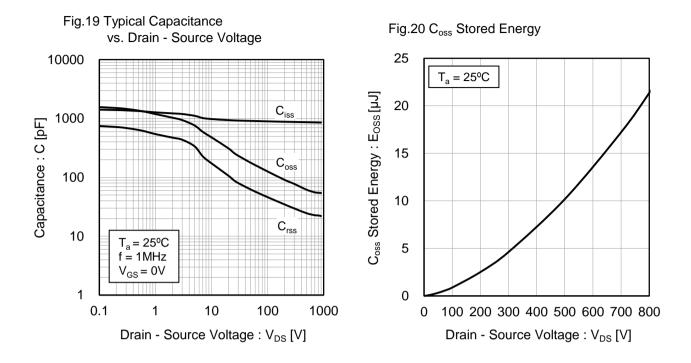
Fig.14 Transconductance vs. Drain Current



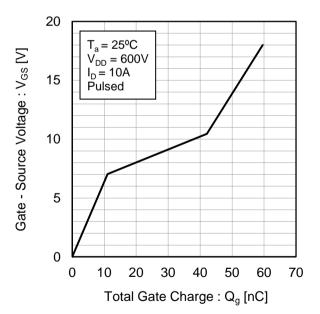


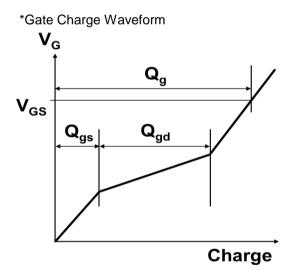


ROHM

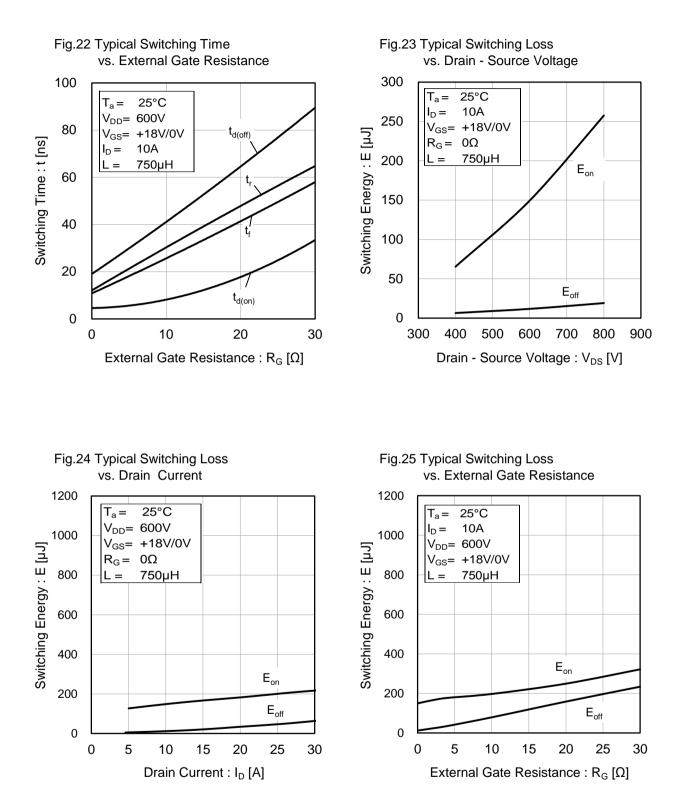


#### Fig.21 Dynamic Input Characteristics













# Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

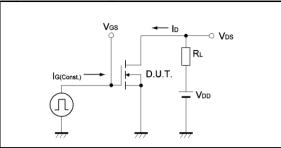


Fig.2-1 Switching Characteristics Measurement Circuit

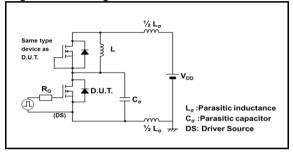


Fig.2-3 Waveforms for Switching Energy Loss

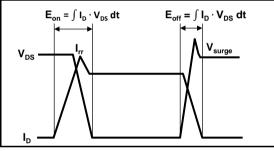


Fig.3-1 Reverse Recovery Time Measurement Circuit

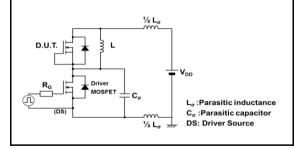


Fig.2-2 Waveforms for Switching Time

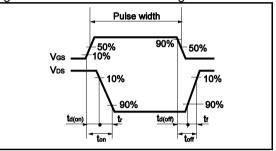
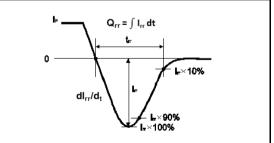


Fig.3-2 Reverse Recovery Waveform





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